

PSMN2R4-30MLD

N-channel 30 V, 2.4 m Ω logic level MOSFET in LFPAK33 using NextPowerS3 Technology

11 August 2015

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in LFPAK33 package. NextPowerS3 portfolio utilising Nexperia's unique "SchottkyPlus" technology delivers high efficiency, low spiking performance usually associated with MOSFETs with an integrated Schottky or Schottky-like diode but without problematic high leakage current. NextPowerS3 is particularly suited to high efficiency applications at high switching frequencies.

2. Features and benefits

- Ultra low Q_G, Q_{GD} and Q_{OSS} for high system efficiency, especially at higher switching frequencies
- Superfast switching with soft-recovery; s-factor > 1
- Low spiking and ringing for low EMI designs
- Unique "SchottkyPlus" technology; Schottky-like performance with < 1 μA leakage at 25 °C
- Optimised for 4.5 V gate drive
- Low parasitic inductance and resistance
- High reliability clip bonded and solder die attach Mini Power SO8 package; no glue, no wire bonds, gualified to 175 °C
- Exposed leads for optimal visual solder inspection

3. Applications

- On-board DC-to-DC solutions for server and telecommunications
- Secondary-side synchronous rectification in telecommunication applications
- Voltage regulator modules (VRM)
- Point-of-Load (POL) modules
- Power delivery for V-core, ASIC, DDR, GPU, VGA and system components
- Brushed and brushless motor control

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------|-------------------------|--|-----|-----|-----|-----|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | | - | - | 30 | V |
| I _D | drain current | T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 2</u> | [1] | - | - | 70 | Α |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 1</u> | | - | - | 91 | W |



| Symbol | Parameter | Conditions | M | in | Тур | Max | Unit |
|---------------------|----------------------------------|---|----|----|------|-----|------|
| T _j | junction temperature | | -5 | 55 | - | 175 | °C |
| Static charact | eristics | | | | | | |
| R _{DSon} | drain-source on-state resistance | V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 10 | - | | 2.6 | 3.2 | mΩ |
| | | V_{GS} = 10 V; I_{D} = 25 A; T_{j} = 25 °C; Fig. 10 | - | | 2 | 2.4 | mΩ |
| Dynamic char | acteristics | | | | | | |
| Q_{GD} | gate-drain charge | V_{GS} = 4.5 V; I_D = 25 A; V_{DS} = 15 V; Fig. 12; Fig. 13 | - | | 5.6 | 8.4 | nC |
| Q _{G(tot)} | total gate charge | V_{GS} = 4.5 V; I_D = 25 A; V_{DS} = 15 V; Fig. 12; Fig. 13 | - | | 16 | 24 | nC |
| Source-drain | diode | | | | | | |
| S | softness factor | I_S = 25 A; V_{GS} = 0 V; dI_S/dt = -100 A/ μ s; V_{DS} = 15 V; Fig. 16 | - | | 0.97 | - | |

^[1] Continuous current is limited by package

5. Pinning information

Table 2. Pinning information

| | | | | · |
|-----|--------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | S | source | | D |
| 2 | S | source | | |
| 3 | S | source | | G T |
| 4 | G | gate | | mbb076 S |
| mb | D | mounting base; connected to drain | LFPAK33 (SOT1210) | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|---------------|---------|---|---------|
| | Name | Description | Version |
| PSMN2R4-30MLD | LFPAK33 | Plastic single ended surface mounted package (LFPAK33); 8 leads | SOT1210 |

Marking 7.

Table 4. **Marking codes**

| Type number | Marking code |
|---------------|--------------|
| PSMN2R4-30MLD | 2D430L |

Limiting values 8.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|----------------------|--|---|-----|-----|-----|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | | - | 30 | V |
| V_{DGR} | drain-gate voltage | 25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ | | - | 30 | V |
| V_{GS} | gate-source voltage | | | -20 | 20 | V |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 1</u> | | - | 91 | W |
| I _D | drain current | V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u> | [1] | - | 70 | Α |
| | | V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u> | [1] | - | 70 | Α |
| I _{DM} | peak drain current | pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3 | | - | 580 | Α |
| T _{stg} | storage temperature | | | -55 | 175 | °C |
| Tj | junction temperature | | | -55 | 175 | °C |
| T _{sld(M)} | peak soldering temperature | | | - | 260 | °C |
| Source-dra | in diode | | 1 | · | | |
| Is | source current | T _{mb} = 25 °C | [1] | - | 70 | Α |
| I _{SM} | peak source current | pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$ | | - | 580 | Α |
| Avalanche | ruggedness | | 1 | ' | ' | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 25 A; V_{sup} ≤ 30 V; R_{GS} = 50 Ω ; unclamped; t_p = 419 μs | [2] | - | 204 | mJ |

Continuous current is limited by package Protected by 100% test

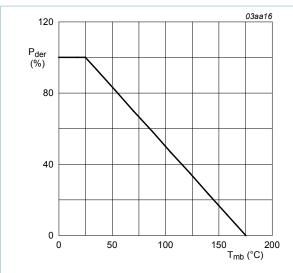
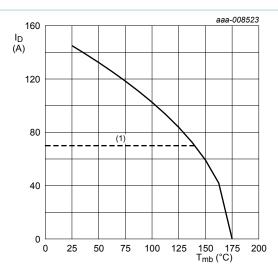


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$



(1) Capped at 70A due to package

Fig. 2. Continuous drain current as a function of mounting base temperature

$$V_{GS} \ge 10V$$

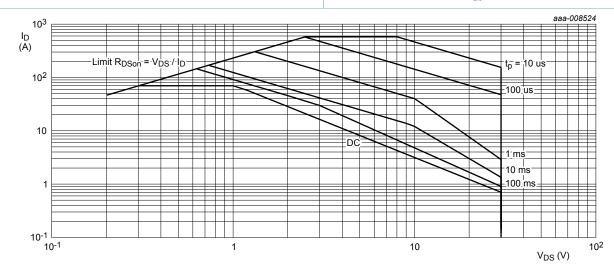


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25^{\circ}C$; I_{DM} is a single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|------------|-----|------|------|------|
| R _{th(j-mb)} | thermal resistance from junction to mounting base | Fig. 4 | - | 1.44 | 1.65 | K/W |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--------------------------|---------------|-----|-----|-----|------|
| R _{th(j-a)} | thermal resistance | <u>Fig. 5</u> | - | 57 | - | K/W |
| | from junction to ambient | Fig. 6 | - | 178 | - | K/W |

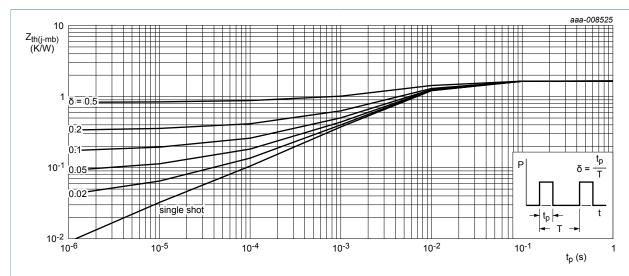


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

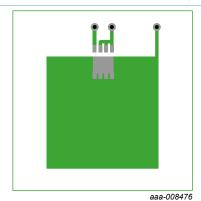


Fig. 5. PCB layout for thermal resistance junction to ambient 1" square pad; FR4 Board; 2oz copper

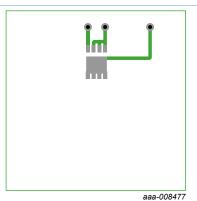


Fig. 6. PCB layout for thermal resistance junction to ambient minimum footprint; FR4 Board; 2oz copper

10. Characteristics

Table 7. Characteristics

| able 1. Sharacteriories | | | | | | | |
|-----------------------------------|--|--|----|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| Static characteristics | | | | | | | |
| V _{(BR)DSS} drain-source | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$ | | 30 | - | - | V | |
| | breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$ | | 27 | - | - | V |
| V _{GS(th)} | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$ | | 1.2 | 1.7 | 2.2 | V |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------------|--|--|-----|------|------|------|
| $\Delta V_{GS(th)}/\Delta T$ | gate-source threshold voltage variation with temperature | 25 °C ≤ T _j ≤ 150 °C | - | -4.3 | - | mV/K |
| I _{DSS} | drain leakage current | V _{DS} = 24 V; V _{GS} = 0 V; T _j = 25 °C | - | - | 1 | μA |
| | | V _{DS} = 24 V; V _{GS} = 0 V; T _j = 125 °C | - | 1.2 | - | μA |
| I _{GSS} | gate leakage current | V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 100 | nA |
| | | V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 100 | nA |
| R _{DSon} | drain-source on-state resistance | V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 10 | - | 2.6 | 3.2 | mΩ |
| | | V _{GS} = 4.5 V; I _D = 25 A; T _j = 150 °C; Fig. 11; Fig. 10 | - | - | 5.3 | mΩ |
| | | V_{GS} = 10 V; I_{D} = 25 A; T_{j} = 25 °C; Fig. 10 | - | 2 | 2.4 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; Fig. 11; Fig. 10 | - | - | 4 | mΩ |
| R_G | gate resistance | f = 1 MHz | - | 0.74 | 1.5 | Ω |
| Dynamic cha | aracteristics | | | ' | ' | |
| Q _{G(tot)} | total gate charge | I _D = 25 A; V _{DS} = 15 V; V _{GS} = 10 V; Fig. 12; Fig. 13 | - | 34 | 51 | nC |
| | | I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13 | - | 16 | 24 | nC |
| | | I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V | - | 31 | - | nC |
| Q _{GS} | gate-source charge | I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V; | - | 5.1 | - | nC |
| Q _{GS(th)} | pre-threshold gate- source charge | Fig. 12; Fig. 13 | - | 3.3 | - | nC |
| Q _{GS(th-pl)} | post-threshold gate- source charge | | - | 1.8 | - | nC |
| Q_{GD} | gate-drain charge | | - | 5.6 | 8.4 | nC |
| $V_{GS(pl)}$ | gate-source plateau voltage | I _D = 25 A; V _{DS} = 15 V; <u>Fig. 12</u> ; <u>Fig. 13</u> | - | 2.7 | - | V |
| C _{iss} | input capacitance | V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz; | - | 2176 | 3264 | pF |
| C _{oss} | output capacitance | T _j = 25 °C; <u>Fig. 14</u> | - | 1150 | 1725 | pF |
| C _{rss} | reverse transfer capacitance | | - | 156 | 234 | pF |
| t _{d(on)} | turn-on delay time | V_{DS} = 15 V; R_L = 0.6 Ω ; V_{GS} = 4.5 V; | - | 15 | - | ns |
| t _r | rise time | $R_{G(ext)} = 5 \Omega$ | - | 23 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 19 | - | ns |
| t _f | fall time | | - | 13 | - | ns |
| | | | | | | |

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------|----------------------------|--|-----|-----|------|------|------|
| Q _{oss} | output charge | $V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$ | | - | 24 | - | nC |
| Source-dra | in diode | | | - 1 | ' | | |
| V_{SD} | source-drain voltage | $I_S = 20 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 15$ | | - | 0.8 | 1.2 | V |
| t _{rr} | reverse recovery time | $I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$ | | - | 31.2 | 62.4 | ns |
| Q _r | recovered charge | V _{DS} = 15 V; <u>Fig. 16</u> | [1] | - | 23.5 | 47 | nC |
| t _a | reverse recovery rise time | | | - | 15.8 | - | ns |
| t _b | reverse recovery fall time | | | - | 15.4 | - | ns |
| S | softness factor | | | - | 0.97 | - | |

[1] includes capacitive recovery

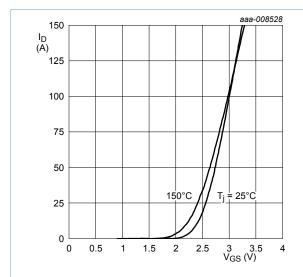


Fig. 7. Transfer characteristics; drain current as a function of gate-source voltage; typical values



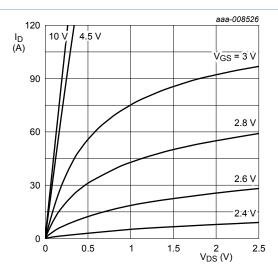


Fig. 8. Output characteristics; drain current as a function of drain-source voltage; typical values

$$T_j = 25$$
°C

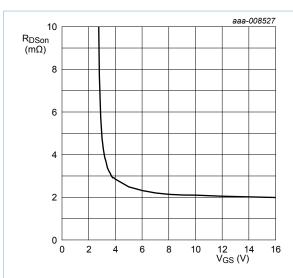


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25^{\circ}C; I_D = 25A$$

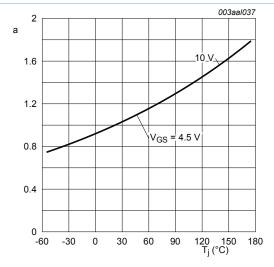


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon (25^{\circ}C)}}$$

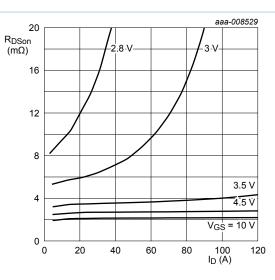


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25^{\circ}C$$

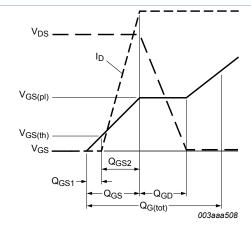


Fig. 12. Gate charge waveform definitions

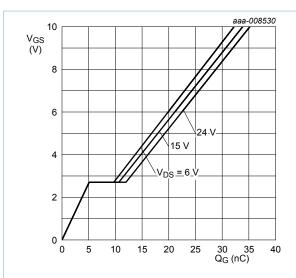


Fig. 13. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}C; I_D = 25A$$

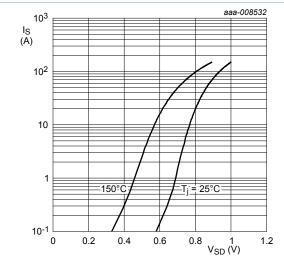


Fig. 15. Source current as a function of source-drain voltage; typical values

$$V_{GS} = 0V$$

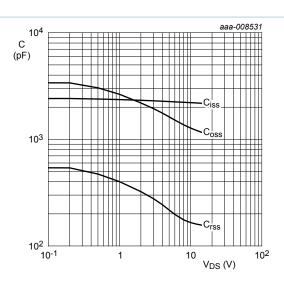


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = \mathbf{0}V; \ f = \mathbf{1}MHz$$

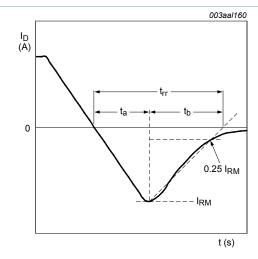
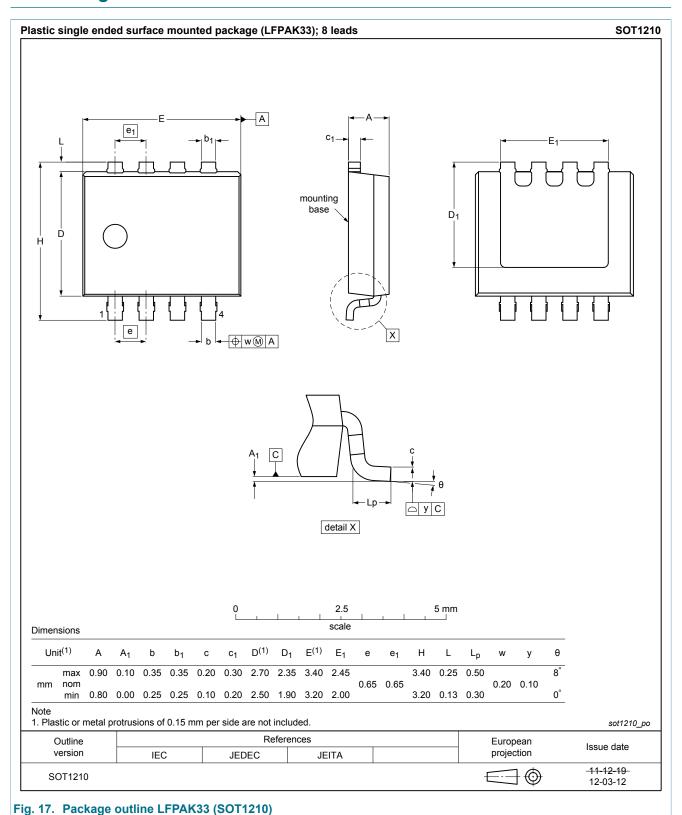


Fig. 16. Reverse recovery timing definition

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11. Package outline



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|--------------------------------------|--------------------|---|
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